

## Postdoc position Qubits in planar Ge

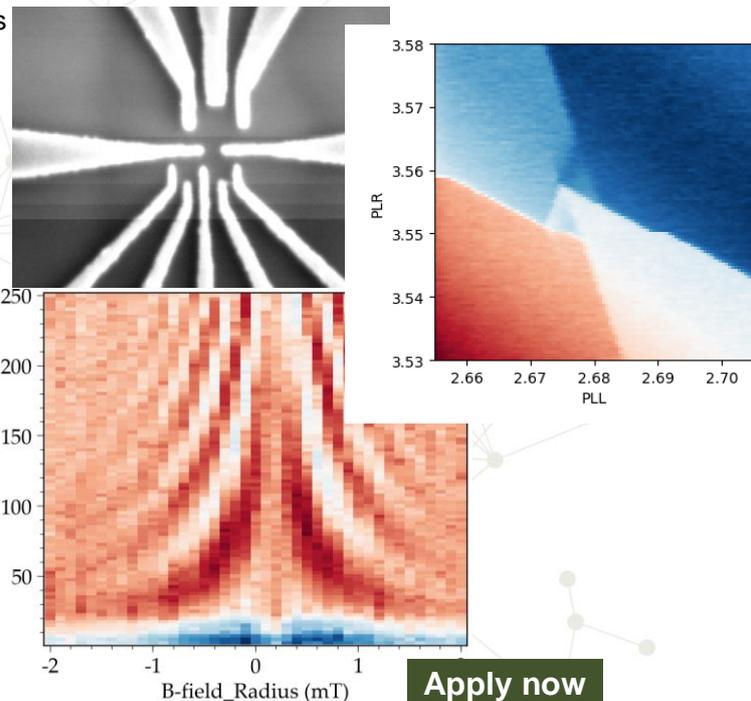
While GaAs structures represent the current state-of-the-art in device complexity, Si devices hold the current records in coherence times due to the nuclear-spin free environment in isotopically purified samples [1,2,3]. Ge which has been much less studied, has recently emerged as a very promising material platform for hosting spin qubits due to the suppressed hyperfine interaction and strong spin orbit coupling [4]. In only three years a single Loss-DiVincenzo qubit [5], 2-qubit and most recently even 4-qubit devices have been demonstrated [6,7].

In our group we have recently realized a hole spin qubit with dephasing times of 1  $\mu$ s operating already at fields of 500  $\mu$ T, within the range of magnetic fields currently used for on-chip biasing of superconducting circuits. This was achieved by using the large out of plane g-factors of holes in Ge and by encoding the qubit in the singlet-triplet states of a double quantum dot device [6]. In this project we aim to use hole qubits in planar Ge devices and make further steps towards the realization of a hole spin based quantum processor.

You will get the chance to work with state of the art qubit devices in a young international institute dedicated to basic research, located in Klosterneuburg on the outskirts of Vienna ([www.ist.ac.at](http://www.ist.ac.at))

### References:

- [1] R. Hanson et al., Rev. Mod. Phys. 79, 1217 (2007).
- [2] F. A. Zwanenburg et al., Rev. Mod. Phys. 85, 961 (2013).
- [3] J. Muhonen et al., Nature Nanotechnology 9, 986 (2014).
- [4] G. Scappucci et al., Nature Reviews Materials (2020).
- [5] H. Watzinger et al., Nature Communications 8, (2018).
- [6]. N. W. Hendrickx et al., Nature 577, 487 (2020).
- [7] N. W. Hendrickx et al., Nature 591, 580 (2021).
- [8] D. Jirovec et al. arXiv: 2011.13755 (2020).



**Apply now**

### Requirements

- High motivation
- Excellent track record in spin or superconducting qubits
- Enjoy working in an international environment
- Solid background in the following areas: microwave techniques, low temperature physics and quantum information

To apply for this position  
send your application  
(including CV and two reference  
letters) by e-mail to:

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